Diode Semiconductor Device - Page 1 of 1



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Inclosure Materia	
Glass	
Overall Length:	
0.200 inches	
Terminal Length:	
1.500 inches	
Overall Diameter:	
0.090 inches	
Joint Electronic D	evice Engineering Council/jedec/case Outline Designation:
Do-35	
Mounting Method	:
Terminal	
Features Provide	d:
Hermetically seale	d case and quality assurance level s
Semiconductor M	aterial:
Silicon	
Voltage Rating In	Volts Per Characteristic:
9.1 regulator volta	nge
Voltage Tolerance	e In Percent:
-5.0/+5.0	
Current Rating Pe	er Characteristic:
47.00 milliamperes	repetitive peak forward current
Power Rating Per	Characteristic:
500.0 milliwatts sm	all-signal input power, common-collector preset
Maximum Operat	ng Tempurature Per Measurement Point:
200.0 degrees cels	ius ambient air
Test Data Docum	ent:
81349-mil-s-19500	specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes c	ommercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and	performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type An	d Quantity:
2 uninsulated wire	lead
Specification Data	3:
81349-mil-s-19500	/533 government specification
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
A110a0	